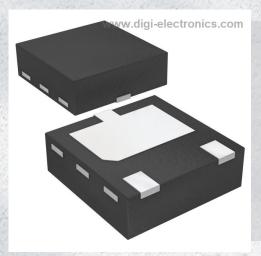


# **BC69-25PASX Datasheet**



https://www.DiGi-Electronics.com

DiGi Electronics Part Number BC69-25PASX-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number BC69-25PASX

Description TRANS PNP 20V 2A DFN2020D-3

**Detailed Description** Bipolar (BJT) Transistor PNP 20 V 2 A 140MHz 420 m

W Surface Mount DFN2020D-3



Tel: +00 852-30501935

RFQ Email: Info@DiGi-Electronics.com

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# **Purchase and inquiry**

Manufacturer Product Number:	Manufacturer:
BC69-25PASX	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
PNP	2 A
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, lc:
20 V	600mV @ 200mA, 2A
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
100nA (ICBO)	85 @ 500mA, 1V
Power - Max:	Frequency - Transition:
420 mW	140MHz
Operating Temperature:	Mounting Type:
150°C (TJ)	Surface Mount
Package / Case:	Supplier Device Package:
3-UDFN Exposed Pad	DFN2020D-3
Base Product Number:	
BC69	

## **Environmental & Export classification**

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



# 20 V, 2 A PNP medium power transistors Rev. 1 — 19 June 2015

**Product data sheet** 

### **Product profile**

#### 1.1 General description

PNP medium power transistors in an ultra thin DFN2020D-3 (SOT1061D) leadless small Surface-Mounted Device (SMD) plastic package with medium power capability and visible and solderable side pads.

NPN complement: BC68PAS series

#### 1.2 Features and benefits

- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- Reduced Printed-Circuit Board (PCB) area requirements
- Exposed heat sink for excellent thermal and electrical conductivity
- AEC-Q101 qualified

- Three current gain selections
- Leadless very small SMD plastic package with medium power capability
- Suitable for Automatic Optical Inspection (AOI) of solder joint

### 1.3 Applications

- Linear voltage regulators
- Battery driven devices
- MOSFET drivers

- High-side switches
- Power management
- Amplifiers

#### 1.4 Quick reference data

**Quick reference data** 

T<sub>amb</sub> = 25 °C unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-20	V
I <sub>C</sub>	collector current		-	-	-2	Α
I <sub>CM</sub>	peak collector current	single pulse; $t_p \le 1$ ms	-	-	-3	Α
h <sub>FE</sub>	DC current gain	$V_{CE} = -1 \text{ V; } I_C = -500 \text{ mA}$	85	-	375	
	h <sub>FE</sub> selection -16	$V_{CE} = -1 \text{ V; } I_C = -500 \text{ mA}$	100	-	250	
	h <sub>FE</sub> selection -25	$V_{CE} = -1 \text{ V; } I_C = -500 \text{ mA}$	160	-	375	

[1] Pulse test:  $t_p \le 300$  ms;  $\delta \le 0.02$ .



20 V, 2 A PNP medium power transistors

### 2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1	base		_
2	emitter	3	3
3	collector	Transparent top view	1

# 3. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
BC69PAS	DFN2020D-3	0-3 plastic thermal enhanced ultra thin small outline	SOT1061D				
BC69-16PAS		package; no leads; 3 terminals; body $2 \times 2 \times 0.65$ mm.					
BC69-25PAS							

### 4. Marking

Table 4. Marking codes

3	
Type number	Marking code
BC69PAS	C1
BC69-16PAS	C2
BC69-25PAS	C3

### 5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CBO}$	collector-base voltage	open emitter	-	-32	V
$V_{CEO}$	collector-emitter voltage	open base	-	-20	V
$V_{EBO}$	emitter-base voltage	open collector	-	-5	V
I <sub>C</sub>	collector current		-	-2	А
I <sub>CM</sub>	peak collector current	$\begin{array}{l} \text{single pulse;} \\ t_p \leq 1 \text{ ms} \end{array}$	-	-3	A
I <sub>B</sub>	base current		-	-0.4	А

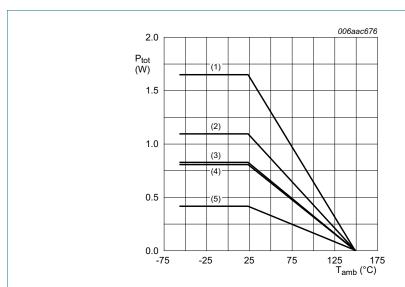
#### 20 V, 2 A PNP medium power transistors

Table 5. Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
P <sub>tot</sub>	total power dissipation	$T_{amb} \le 25  ^{\circ}C$ [1]	-	420	mW
		[2]	-	830	mW
		[3]	-	1.1	W
		[4]	-	810	mW
		[5]	-	1.65	W
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	150	°C
T <sub>stg</sub>	storage temperature		-65	150	°C

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.



- (1) FR4 PCB, 4-layer copper, 1 cm<sup>2</sup>
- (2) FR4 PCB, single-sided copper, 6 cm<sup>2</sup>
- (3) FR4 PCB, single-sided copper, 1 cm<sup>2</sup>
- (4) FR4 PCB, 4-layer copper, standard footprint
- (5) FR4 PCB, single-sided copper, standard footprint

Fig 1. Power derating curves

20 V, 2 A PNP medium power transistors

### 6. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Max	Unit
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	<u>[1]</u>	298	K/W
			[2]	151	K/W
			[3]	114	K/W
			[4]	154	K/W
			[5]	76	K/W
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point	in free air		20	K/W

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm<sup>2</sup>.
- [4] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and standard footprint.
- [5] Device mounted on an FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>

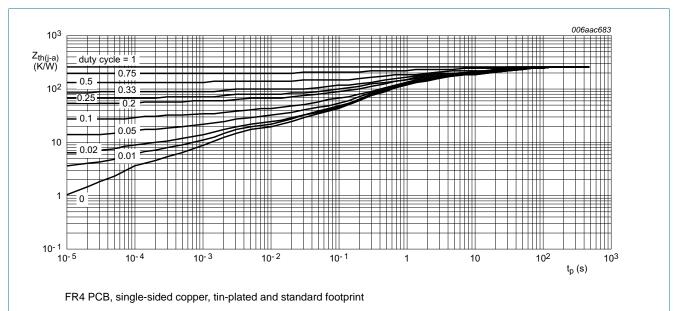
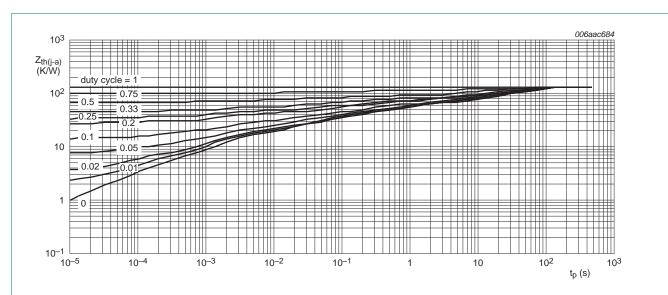


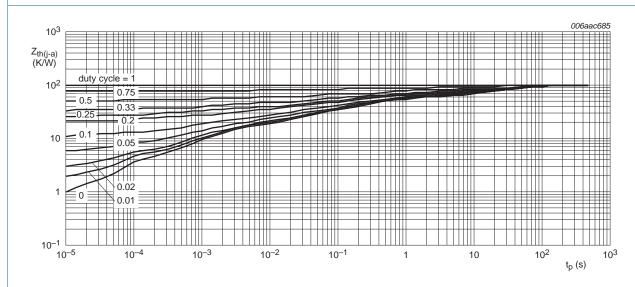
Fig 2. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values

### 20 V, 2 A PNP medium power transistors



FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>

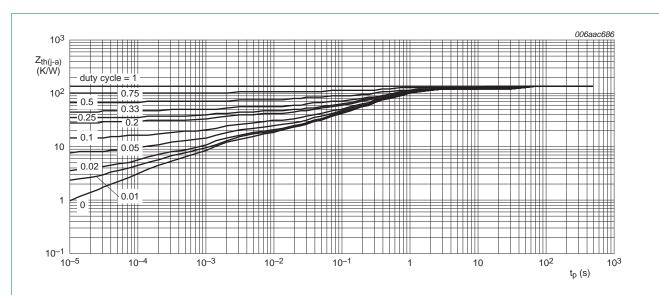
Fig 3. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



FR4 PCB, single-sided copper, tin-plated and mounting pad for collector 6 cm<sup>2</sup>

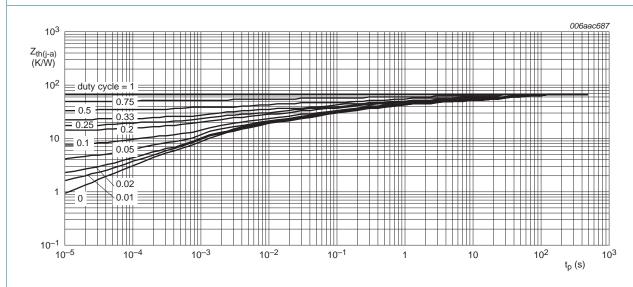
Fig 4. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values

### 20 V, 2 A PNP medium power transistors



FR4 PCB, 4-layer copper, tin-plated and standard footprint

Fig 5. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values



FR4 PCB, 4-layer copper, tin-plated and mounting pad for collector 1 cm<sup>2</sup>

Fig 6. Transient thermal impedance from junction to ambient as a function of pulse duration for; typical values

20 V, 2 A PNP medium power transistors

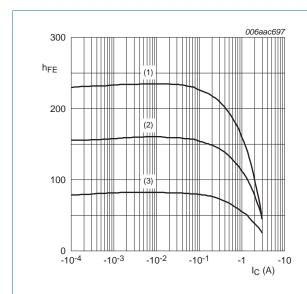
### 7. Characteristics

Table 7. Characteristics

T<sub>amb</sub> = 25 °C unless otherwise specified

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>CBO</sub>	collector-base cut-off current	$V_{CB} = -25 \text{ V}; I_E = 0 \text{ A}$		-	-	-100	nA
		$V_{CB} = -25 \text{ V}; I_E = 0 \text{ A}; T_j = 150 ^{\circ}\text{C}$		-	-	-10	μΑ
I <sub>EBO</sub>	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$		-	-	-100	nA
h <sub>FE</sub>	DC current gain	$V_{CE} = -10 \text{ V; } I_{C} = -5 \text{ mA}$		50	-	-	
		$V_{CE} = -1 \text{ V; } I_{C} = -500 \text{ mA}$	<u>[1]</u>	85	-	375	
		$V_{CE} = -1 \text{ V}; I_{C} = -1 \text{ A}$	<u>[1]</u>	60	-	-	
		$V_{CE} = -1 \text{ V}; I_C = -2 \text{ A}$	<u>[1]</u>	40	-	-	
	h <sub>FE</sub> selection-16	$V_{CE} = -1 \text{ V; } I_{C} = -500 \text{ mA}$	<u>[1]</u>	100	-	250	
	h <sub>FE</sub> selection-25	$V_{CE} = -1 \text{ V; } I_{C} = -500 \text{ mA}$	<u>[1]</u>	160	-	375	
V <sub>CEsat</sub>	collector-emitter saturation	$I_C = -1 \text{ A}; I_B = -100 \text{ mA}$	<u>[1]</u>	-	-	-0.5	V
	voltage	$I_C = -2 \text{ A}; I_B = -200 \text{ mA}$	<u>[1]</u>	-	-	-0.6	V
V <sub>BE</sub>	base-emitter voltage	$I_C = -5 \text{ mA}; V_{CE} = -10 \text{ V}$	<u>[1]</u>	-	-	-0.7	V
		$I_C = -1 A; V_{CE} = -1 V$	<u>[1]</u>	-	-	-1	V
f <sub>T</sub>	transition frequency	$V_{CE} = -5 \text{ V}; I_C = -50 \text{ mA}; f = 100 \text{ MHz}$		40	140	-	MHz
C <sub>c</sub>	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A}; f = 1 \text{ MHz}$		-	28	-	рF

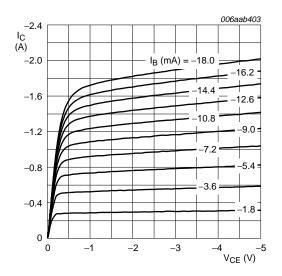
[1] Pulse test:  $t_p \le 300$  ms;  $\delta \le 0.02$ 





- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 7. h<sub>FE</sub> selection -16: DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

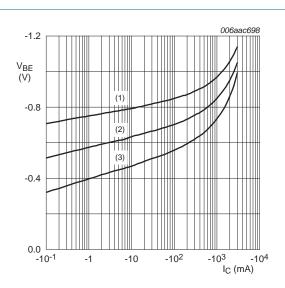
Fig 8. h<sub>FE</sub> selection -16: Collector current as a function of collector-emitter voltage; typical values

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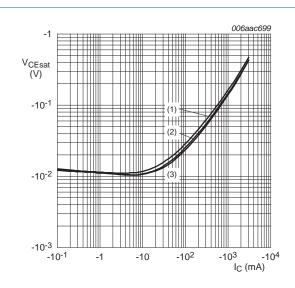
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### 20 V, 2 A PNP medium power transistors



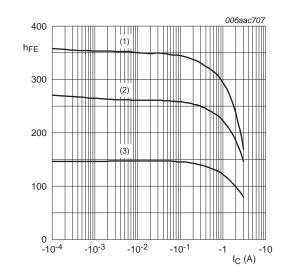
- $V_{CE} = -1 V$
- (1)  $T_{amb} = -55 \,^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 100 \, ^{\circ}C$

Fig 9. h<sub>FE</sub> selection -16: Base-emitter voltage as a function of collector current; typical values



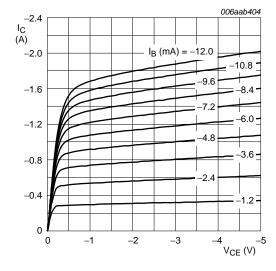
- $I_{\rm C}/I_{\rm B} = 10$
- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 10. h<sub>FE</sub> selection -16: Collector-emitter saturation voltage as a function of collector current; typical values



- $V_{CE} = -1 V$
- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 11. h<sub>FE</sub> selection -25: DC current gain as a function of collector current; typical values



 $T_{amb} = 25 \, ^{\circ}C$ 

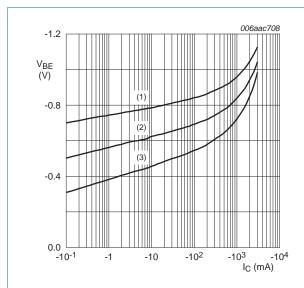
Fig 12. h<sub>FE</sub> selection -25: Collector current as a function of collector-emitter voltage; typical values

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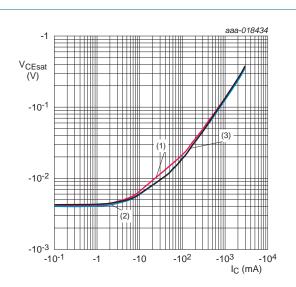
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### 20 V, 2 A PNP medium power transistors



- $V_{CE} = -1 V$
- (1)  $T_{amb} = -55 \,^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = 100 \, ^{\circ}C$

Fig 13. h<sub>FE</sub> selection -25: Base-emitter voltage as a function of collector current; typical values



- $I_{\rm C}/I_{\rm B} = 10$
- (1)  $T_{amb} = 100 \, ^{\circ}C$
- (2)  $T_{amb} = 25 \, ^{\circ}C$
- (3)  $T_{amb} = -55 \, ^{\circ}C$

Fig 14. h<sub>FE</sub> selection -25: Collector-emitter saturation voltage as a function of collector current; typical values

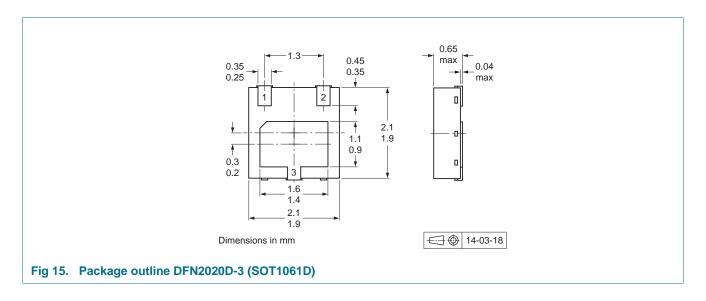
### 8. Test information

### 8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

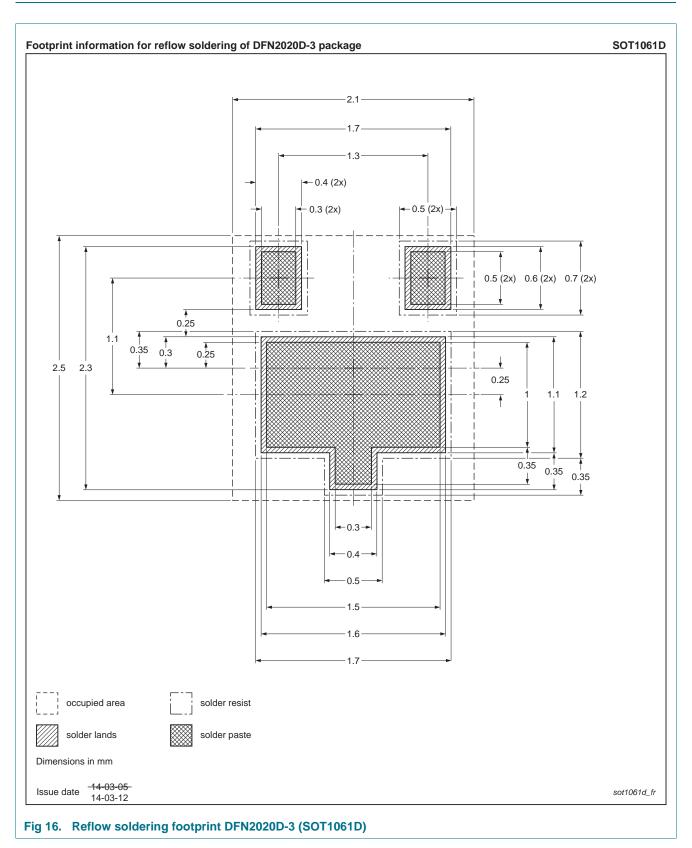
20 V, 2 A PNP medium power transistors

### 9. Package outline



20 V, 2 A PNP medium power transistors

### 10. Soldering



### **Nexperia**

# **BC69PAS** series

20 V, 2 A PNP medium power transistors

## 11. Revision history

#### Table 8. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BC69PAS_SER v.1	20150619	Product data sheet	-	-

#### 20 V, 2 A PNP medium power transistors

### 12. Legal information

#### 12.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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### **Nexperia**

## **BC69PAS** series

#### 20 V, 2 A PNP medium power transistors

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**Product data sheet** 

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### **Nexperia**

# **BC69PAS** series

### 20 V, 2 A PNP medium power transistors

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